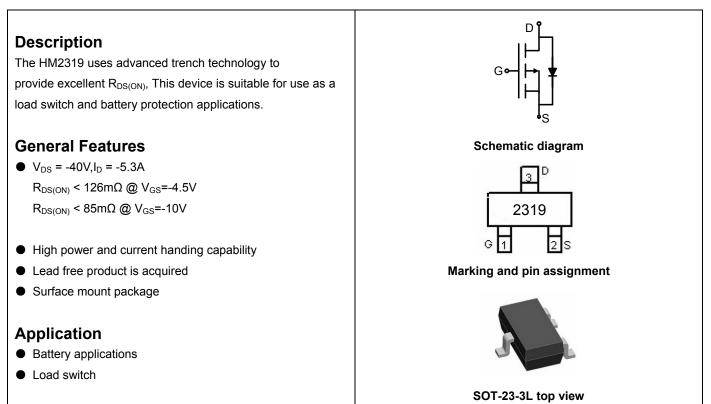


P-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2319	HM2319	SOT-23-3L	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25[°]Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-40	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	-5.3	А
Drain Current-Pulsed (Note 1)	I _{DM}	-20	А
Maximum Power Dissipation	PD	2.0	W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)R _{0JA} 62.5°C/W

Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-40	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-40V, V_{GS} =0V	-	-	-1	μA



Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)				•	•	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$		-1.5	-3	V
	P	V _{GS} =-10V, I _D =-5A -		73	85	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-4A -		98	126	mΩ
Forward Transconductance	g fs	V _{DS} =-5V,I _D =-4.1A		-	-	S
Dynamic Characteristics (Note4)	·			•		
Input Capacitance	C _{lss}	<u> </u>	-	650	-	PF
Output Capacitance	C _{oss}	V _{DS} =-20V,V _{GS} =0V, F=1.0MHz	-	90	-	PF
Reverse Transfer Capacitance	C _{rss}		-	70	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	9	-	nS
Turn-on Rise Time	tr	V_{DD} =-20V, , R_L =2 Ω	-	8	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10V, R_{GEN} =3 Ω	-	28	-	nS
Turn-Off Fall Time	t _f		-	10	-	nS
Total Gate Charge	Qg	V _{DS} =-20V,I _D =-3.1A,	-	14	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =-20V,I _D =-3.1A, V _{GS} =-10V	-	2.9	-	nC
Gate-Drain Charge	Q _{gd}	v _{GS} 10v	-	3.8	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-2.5A	-	0.8	1.2	V
Diode Forward Current (Note 2)	Is		-	-	-5.3	А

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

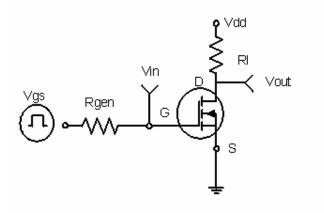


Figure 1:Switching Test Circuit

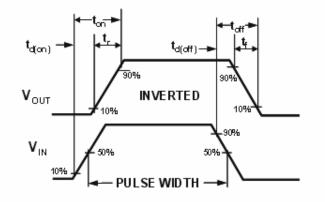
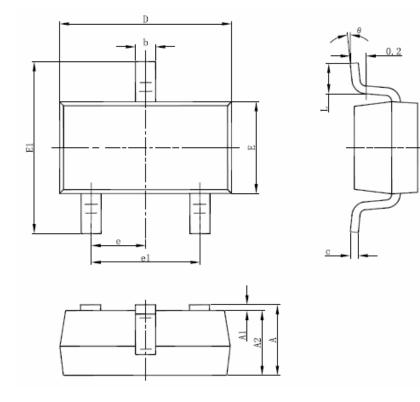


Figure 2:Switching Waveforms



SOT-23-3L Package Information



Symbol	Dimensions Ir	n Millimeters	Dimensions In Inches			
Symbol	Min	Max	Min	Max		
A	1.050	1.250	0.041	0.049		
A1	0.000	0.100	0.000	0.004		
A2	1.050	1.150	0.041	0.045		
b	0.300	0.500	0.012	0.020		
с	0.100	0.200	0.004	0.008		
D	2.820	3.020	0.111	0.119		
E	1.500	1.700	0.059	0.067		
E1	2.650	2.950	0.104	0.116		
e	0.950	(BSC)	0.037(0.037(BSC)		
e1	1.800	2.000	0.071	0.079		
L	0.300	0.600	0.012	0.024		
θ	0°	8°	0°	8°		

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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